



Surface Mount Schottky Barrier Rectifier

Reverse Voltage - 20 to 200V

Forward Current - 2.0A

**FEATURES**

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

**PINNING**

PIN	DESCRIPTION
1	Cathode
2	Anode



Top View  
Simplified outline SMB and symbol

**MECHANICAL DATA**

- Case : SMB
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.055g / 0.002oz

**Absolute Maximum Ratings and Electrical characteristics**

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

Parameter	Symbols	SS22B	SS24B	SS26B	SS28B	SS210B	SS212B	SS215B	SS220B	Units					
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	20	40	60	80	100	120	150	200	V					
Maximum RMS voltage	$V_{RMS}$	14	28	42	56	70	84	105	140	V					
Maximum DC Blocking Voltage	$V_{DC}$	20	40	60	80	100	120	150	200	V					
Maximum Average Forward Rectified Current	$I_{F(AV)}$	2.0								A					
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	$I_{FSM}$	55				45				A					
Max Instantaneous Forward Voltage at 2 A	$V_F$	0.55		0.70		0.85		0.95		V					
Maximum DC Reverse Current $T_a = 25^\circ C$ at Rated DC Reverse Voltage $T_a = 100^\circ C$	$I_R$	0.5 5		0.3 3						mA					
Typical Junction Capacitance <sup>(1)</sup>	$C_j$	220			110					pF					
Typical Thermal Resistance <sup>(2)</sup>	$R_{\theta JA}$	60								°C/W					
Operating Junction Temperature Range	$T_j$	-55 ~ +125								°C					
Storage Temperature Range	$T_{stg}$	-55 ~ +150								°C					

( 1 ) Measured at 1 MHz and applied reverse voltage of 4 V D.C

( 2 ) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.



Fig.1 Forward Current Derating Curve

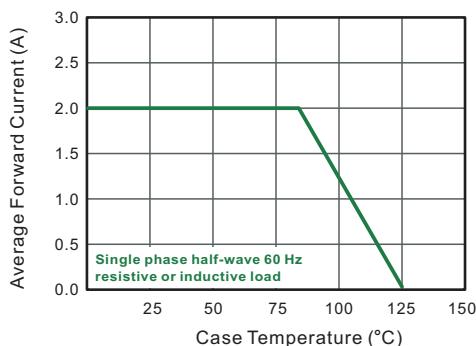


Fig.2 Typical Reverse Characteristics

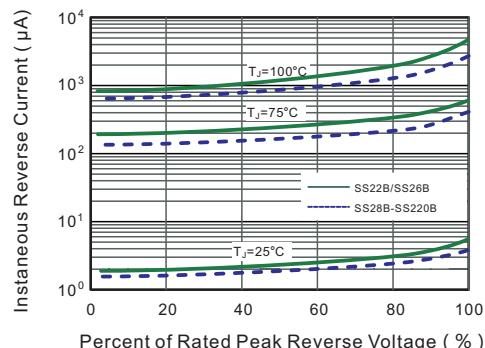


Fig.3 Typical Forward Characteristic

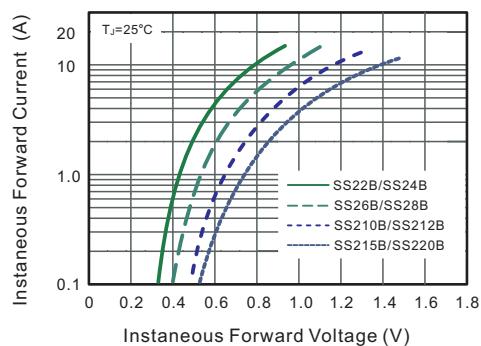


Fig.4 Typical Junction Capacitance

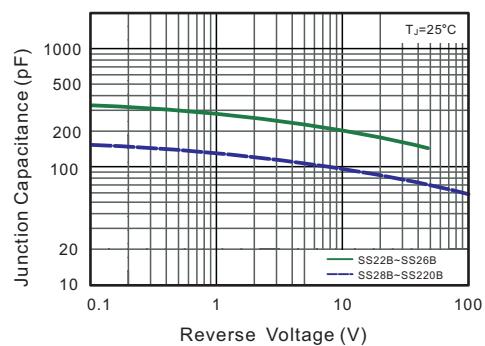


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

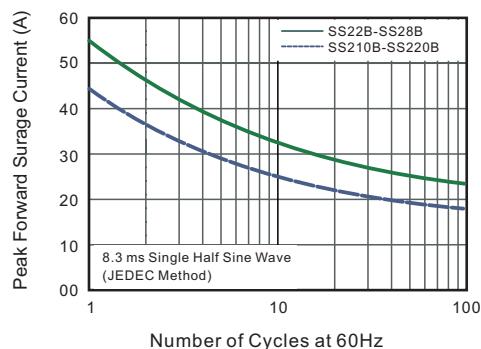
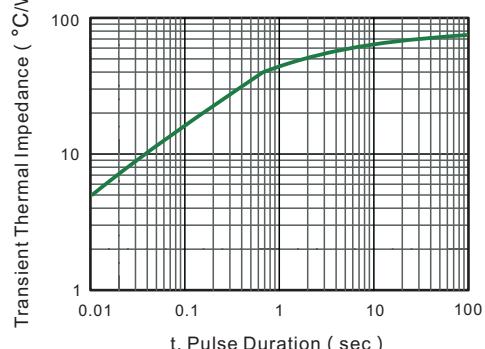


Fig.6- Typical Transient Thermal Impedance

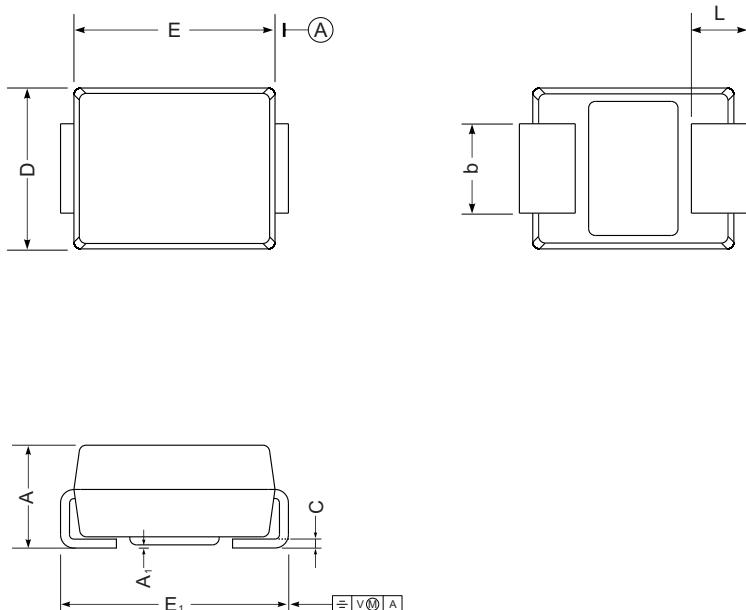




## PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

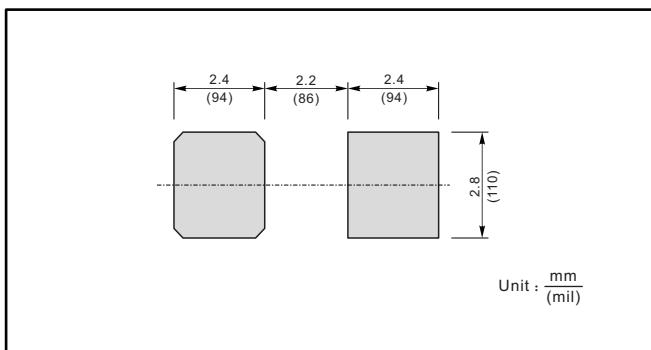
SMB



SMB mechanical data

UNIT		A	E	D	$E_1$	$A_1$	L	C	b
mm	max	2.44	4.70	3.94	5.59	0.20	1.5	0.305	2.2
	min	2.13	4.06	3.3	5.08	0.05	0.8	0.152	1.9
mil	max	96	185	155	220	7.9	59	12	87
	min	84	160	130	200	2.0	32	6	75

### The recommended mounting pad size



### Marking

Type number	Marking code
SS22B	SS22
SS24B	SS24
SS26B	SS26
SS28B	SS28
SS210B	SS210
SS212B	SS212
SS215B	SS215
SS220B	SS220

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